

# SK 9 DGD 065 ET



**SEMITOP® 3**

3-phase bridge rectifier +  
3-phase bridge inverter

**SK 9 DGD 065 ET**

Preliminary Data

## Features

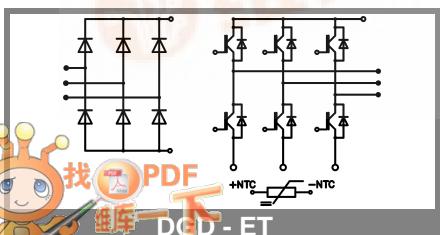
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminum oxide ceramic (DCB)
- Ultrafast NPT technology IGBT
- CAL Technology FWD
- Integrated NTC temperature sensor

## Typical Applications

- Inverter

		$T_s = 25^\circ\text{C}$ , unless otherwise specified		
Symbol	Conditions	Values	Units	
<b>IGBT - Inverter</b>				
$V_{CES}$		600	V	
$I_C$	$T_s = 25 (80)^\circ\text{C}$	12 (8)	A	
$I_{CRM}$	$I_{CRM} = 2 \times I_{Cnom}, t_p = 1 \text{ ms}$	12	A	
$V_{GES}$		$\pm 20$	V	
$T_j$		-40 ... +150	°C	
<b>Diode - Inverter</b>				
$I_F$	$T_s = 25 (80)^\circ\text{C}$	20 (13)	A	
$I_{FRM}$	$I_{FRM} = 2 \times I_{Fnom}, t_p = 1 \text{ ms}$	16	A	
$T_j$		-40 ... +150	°C	
<b>Rectifier</b>				
$V_{RRM}$		800	V	
$I_F$	$T_s = 80^\circ\text{C}$	25	A	
$I_{FSM} / I_{TSM}$	$t_p = 10 \text{ ms}, \sin 180^\circ, T_j = 25^\circ\text{C}$	220	A	
$I_t^2$	$t_p = 10 \text{ ms}, \sin 180^\circ, T_j = 25^\circ\text{C}$	240	A²s	
$T_j$		-40 ... +150	°C	
$T_{sol}$	Terminals, 10s	260	°C	
$T_{stg}$		-40 ... +125	°C	
$V_{isol}$	AC, 1 min. / 1s	2500 / 3000	V	

		$T_s = 25^\circ\text{C}$ , unless otherwise specified		
Symbol	Conditions	min.	typ.	max.
<b>IGBT - Inverter</b>				
$V_{CEsat}$	$I_C = 6 \text{ A}, T_j = 25 (125)^\circ\text{C}$	3	2 (2,2)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 0,5 \text{ mA}$		4	V
$V_{CE(TO)}$	$T_j = 25^\circ\text{C} (125)^\circ\text{C}$		1,2 (1,1)	V
$r_T$	$T_j = 25^\circ\text{C} (125)^\circ\text{C}$		133 (183)	mΩ
$C_{ies}$	$V_{CE} = V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,35	nF
$C_{oes}$	$V_{CE} = V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,4	nF
$C_{res}$	$V_{CE} = V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,25	nF
$R_{th(j-s)}$	per IGBT		2,6	K/W
$t_{d(on)}$	under following conditions		20	ns
$t_r$	$V_{CC} = 300 \text{ V}, V_{GE} = \pm 15 \text{ V}$		25	ns
$t_{d(off)}$	$I_C = 6 \text{ A}, T_j = 125^\circ\text{C}$		145	ns
$t_f$	$R_{Gon} = R_{Goff} = 120 \Omega$		25	ns
$E_{on}$	inductive load		0,22	mJ
$E_{off}$			0,12	mJ
<b>Diode - Inverter</b>				
$V_F = V_{EC}$	$I_F = 8 \text{ A}, T_j = 25 (125)^\circ\text{C}$		1,35	V
$V_{(TO)}$	$T_j = 25^\circ\text{C} (125)^\circ\text{C}$		(0,8)	V
$r_T$	$T_j = 25^\circ\text{C} (125)^\circ\text{C}$		(44)	mΩ
$R_{th(j-s)}$	per diode		2,7	K/W
$I_{RRM}$	under following conditions		4,2	A
$Q_{rr}$	$I_F = 8 \text{ A}, V_R = 300 \text{ V}$		0,65	μC
$E_{rr}$	$V_{GE} = 0 \text{ V}, T_j = 125^\circ\text{C}$			mJ
$di_F/dt$	$= -120 \text{ A}/\mu\text{s}$			
<b>Diode rectifier</b>				
$V_F$	$I_F = 20 \text{ A}, T_j = 25^\circ\text{C}$		1,1	V
$V_{(TO)}$	$T_j = 150^\circ\text{C}$		0,85	V
$r_T$	$T_j = 150^\circ\text{C}$		15	mΩ
$R_{th(j-s)}$	per diode		2,15	K/W
<b>Temperatur sensor</b>				
$R_{ts}$	$5\%, T_r = 25 (100)^\circ\text{C}$		5000(493)	Ω
<b>Mechanical data</b>				
$w$		31	g	
$M_s$	Mounting torque	2,3	2,5	Nm



# SK 9 DGD 065 ET CONVERTER, INVERTER, BRAKE

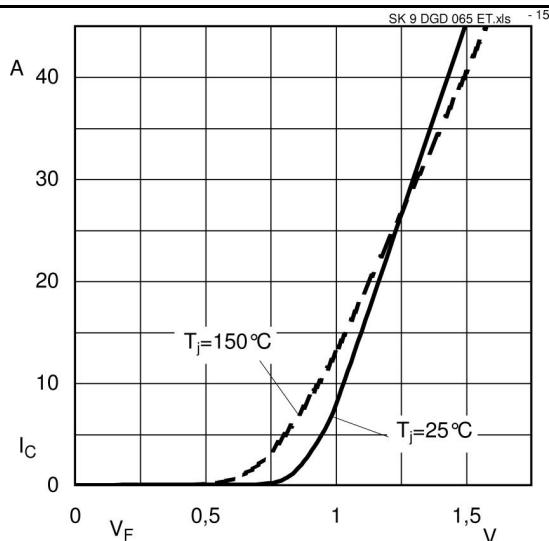


Fig. 15 Typ. Input Bridge Diode forward characteristic

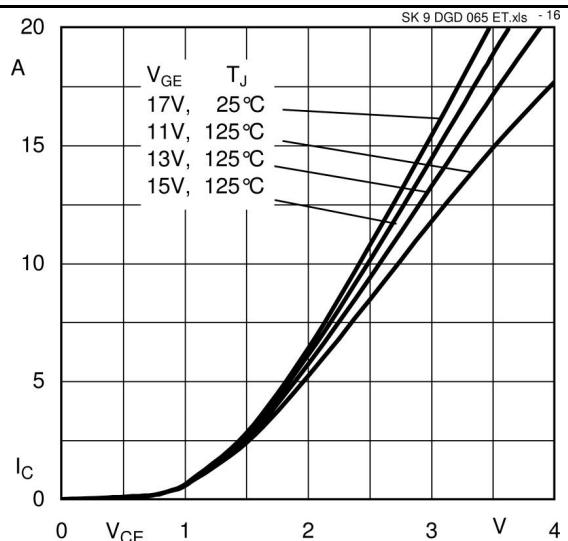


Fig. 16 Typical Output Characteristic

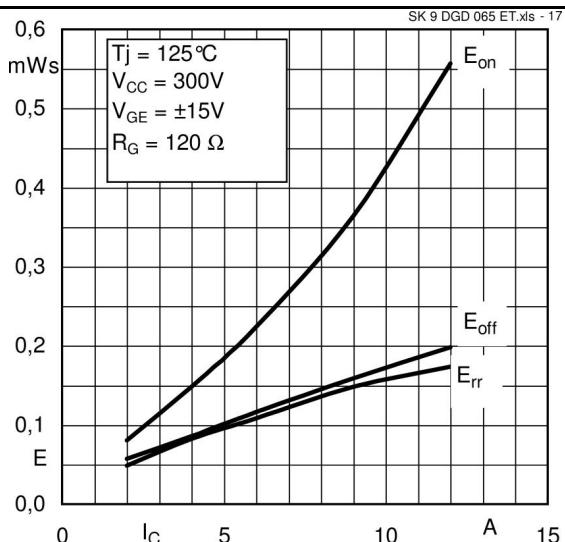


Fig. 17 Turn-On/Off Energy = f ( $I_c$ )

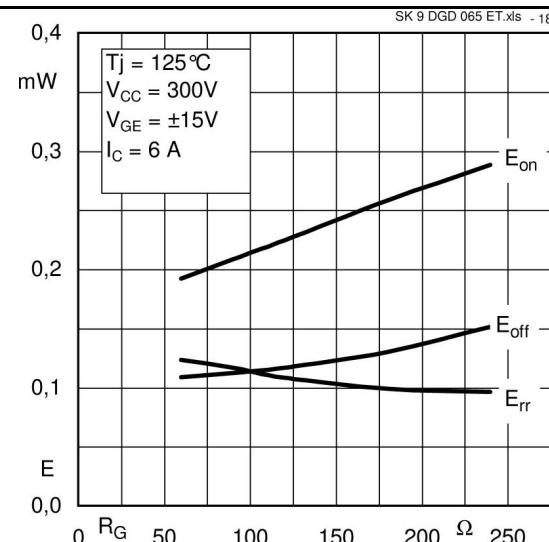


Fig. 18 Turn-On/Off Energy = f ( $R_g$ )

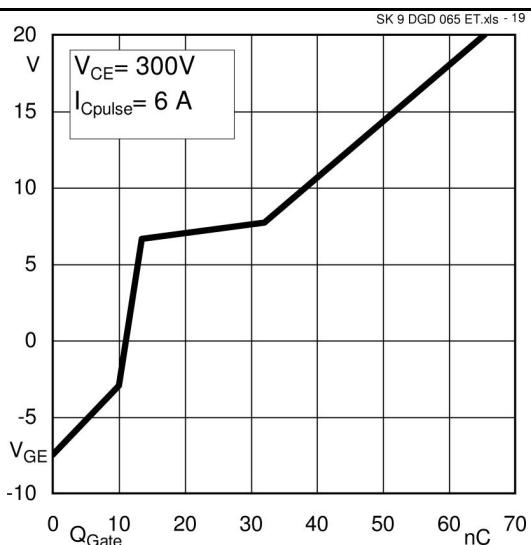


Fig. 19 Typical Gate Charge Characteristic

# SK 9 DGD 065 ET CONVERTER, INVERTER, BRAKE

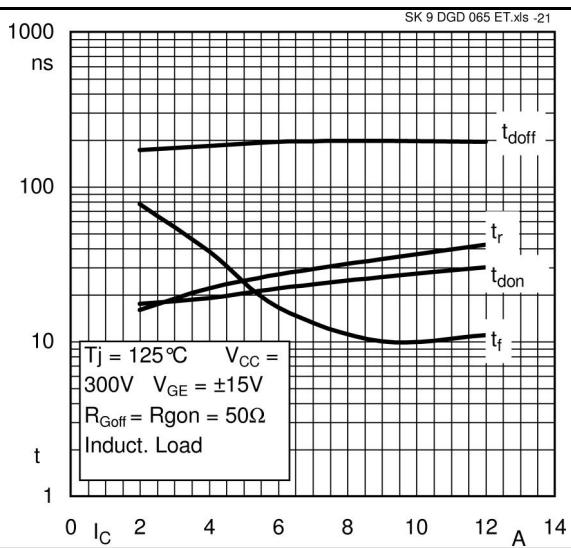


Fig. 21 Typical Switching Times vs.  $I_C$

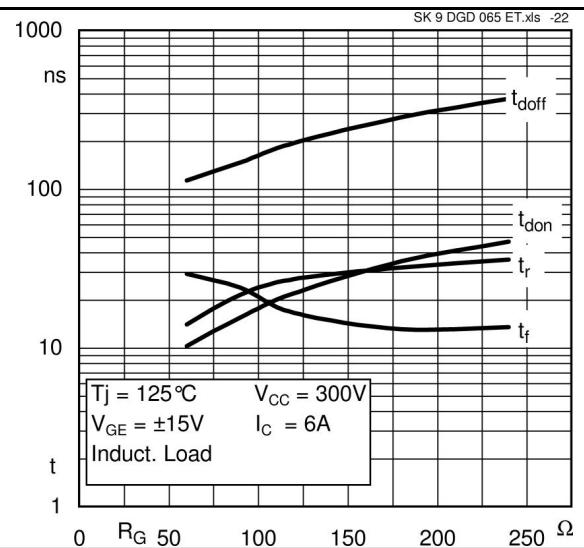


Fig. 22 Typical Switching Times vs. gate resistor  $R_G$

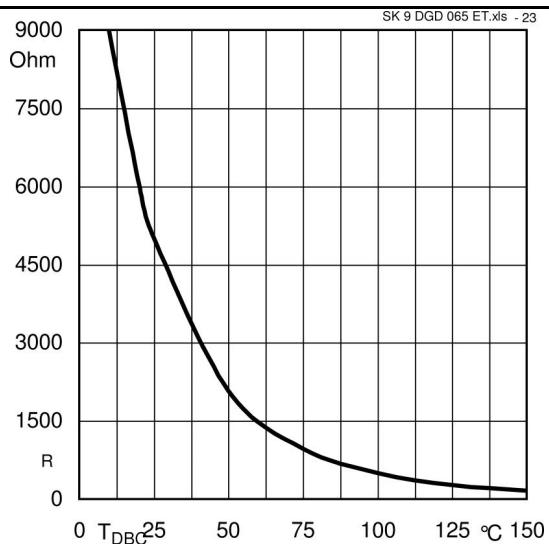


Fig. 23 Typical NTC Characteristic

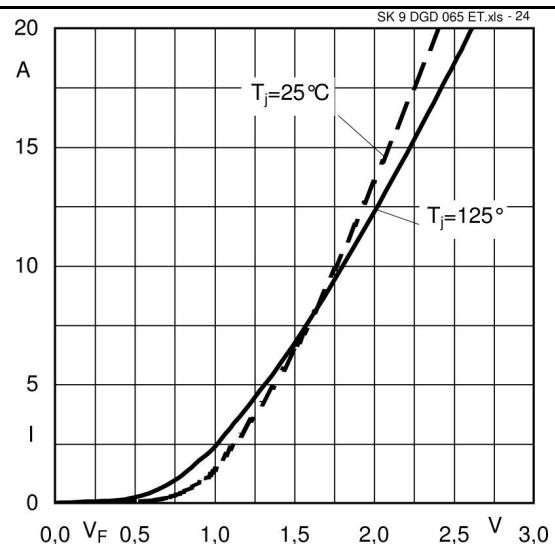
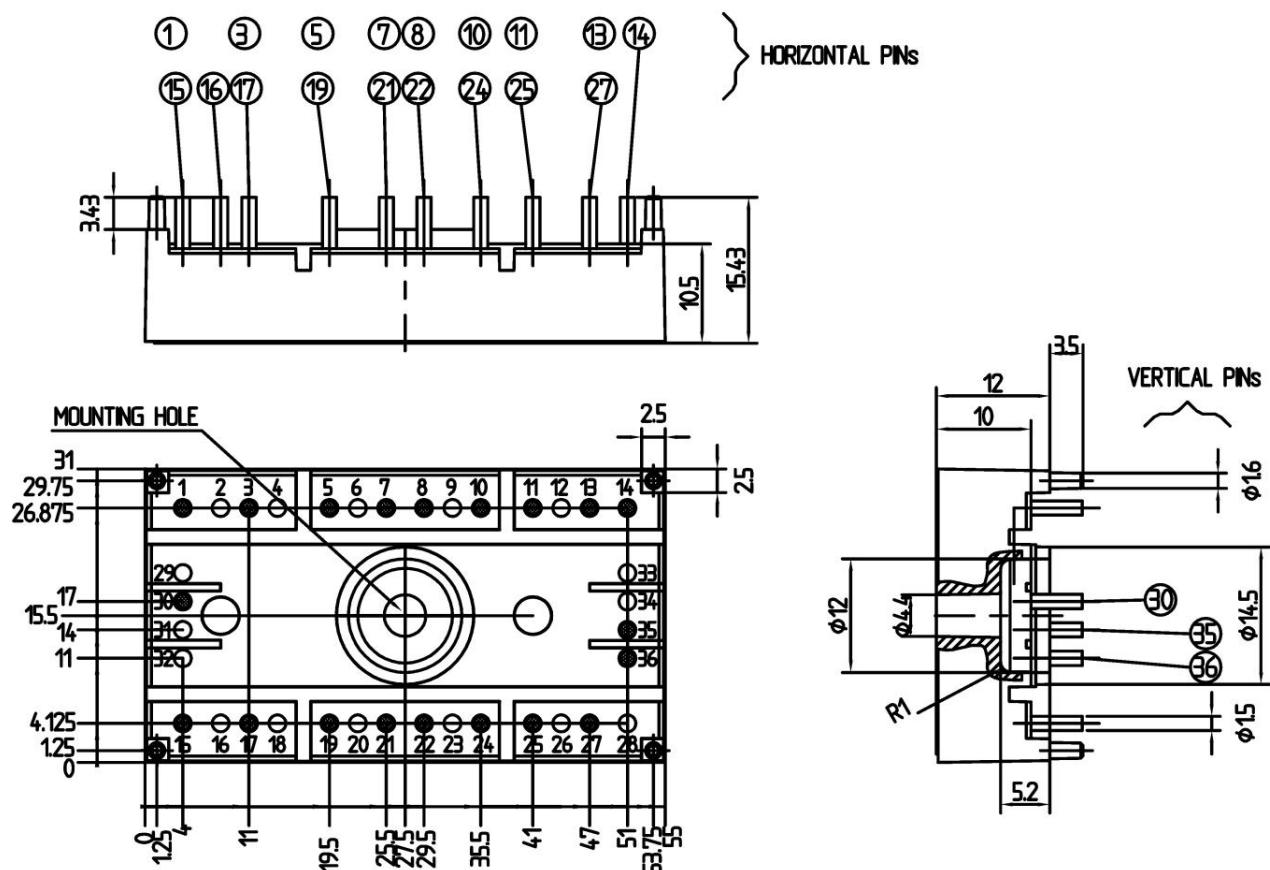


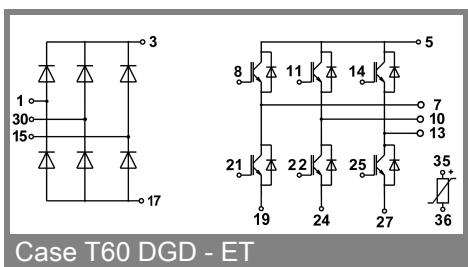
Fig. 24 Typical FWD forward Characteristic

# SK 9 DGD 065 ET CONVERTER, INVERTER, BRAKE

Dimensions in mm



Case T60 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T60 DGD - ET

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.